

NPS1000

0.5 V to 1.0 V, 1.5 A peak, 11 m Ω , load switch

Rev. 1 — 29 March 2024

1. General description

NPS1000 is a low voltage, single-channel load switch with a low $R_{DS,ON}$ (11 m Ω) to minimize IR drop and power loss. It supports up to 0.6 A RMS current and a peak current of 1.5 A.

The switch is controlled by an EN input which is compatible with 1.2 V logic levels. When the load switch is enabled, the internal switch charges the output capacitor with a controlled inrush current. When the switch is disabled, an 8 Ω on-chip resistor discharges the output to ground and keeps it from floating.

The IC is powered from a separate BIAS pin which is rated for 2.3 V to 5.0 V operation.

NPS1000 has an over-temperature protection that latches the device OFF when the internal junction temperature is above the set point ($T_{th(OTLO)}$). At this time, the internal switch is turned off and the output discharge element turns on to discharge the output capacitor. The load switch can be enabled again by toggling the EN pin.

NPS1000 is available in an ultra-small, space saving, wafer level chip-scale package; 8 bumps; 1.42 mm × 0.72 mm × 0.465 mm body and is characterized for operation over junction temperature range of -40 °C to 105 °C.



2. Features and benefits

- 0.5 V 1.0 V operation voltage
- Low R_{DS,ON}: 11 mΩ typical at 25 °C, 16 mΩ (maximum) at 85 °C
- Enable logic supports 1.2 V logic levels
- 0.6 A RMS and 1.5 A peak current capability
- Controlled start-up
 - <200 µs from enable to full enhancement of power FET
- Output short tolerant
 - When supplied by a 4.5 A current limited power supply
- Over-temperature shutdown and input UVLO protection
- 8 Ω discharge while disabled
- Small package footprint
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2
 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C2a exceeds 500 V
- Specified from T_J = -40 °C to +105 °C

3. Applications

- Mobile phones
- Wearables



4. Ordering information

Table 1. Ordering information				
Type number Package				
	Temperature range	Name	Description	Version
NPS1000UP	-40 °C to +105 °C	WLCSP8	wafer level chip-scale package; 8 bumps; 1.42 × 0.72 × 0.465 (max) mm body	WLCSP8_SOT8068

5. Marking

Table 2. Marking		
Type number	Marking code	
NPS1000UP	sC	

6. Functional diagram



7. Pinning information

7.1. Pinning



7.2. Pin description

Table 3. Pin description

Symbol	Bump	Туре	Description
IN	B1, C1	1	Device input. Apply a 0.5 V to 1.0 V voltage source. Bypass with a low ESR capacitor to GND.
OUT	B2, C2	0	Device output. Connect to the load. Bypass with a low ESR capacitor to GND.
BIAS	A1	I	Power supply for the IC. Bypass with a low ESR capacitor to GND.
EN	D1	0	Enable input to the IC. Drive with a 1.2 V logic signal. When EN is high, the main switch is ON and QOD is off, as long as BIAS and temperature are within normal operating ranges. When EN is low, the main switch is turned OFF and QOD is turned ON.
GND	A2, D2	-	Ground (0 V)

8. Functional description

8.1. Overview

The NPS1000 is a load switch with a 11 m Ω N-channel MOSFET designed to operate up to 1.5 A peak current. It is designed for very low inputs of 0.5 V to 1.0 V and the logic input is designed to compatible to 1.2 V logic levels.

The NMOS power FET is placed between the IN and OUT pins and controls the flow of current from IN to OUT. The load switch is powered from the voltage source at the BIAS input and controlled using the EN pin. The OUT pins also have an 8 Ω Quick Output Discharge (QOD) FET internally, which discharges the output to GND when the load switch is OFF and prevents the output from floating. When EN goes high, QOD is turned off and the NMOS power FET is turned on in a controlled manner to control the inrush current.

The IC has a built-in Over Temperature Lock Out (OTLO) that latches off the NMOS when the junction temperature exceeds the OTP threshold. The power FET can be turned back on by toggling the EN input.

8.2. Operation

The IC is turned-on when the voltage at BIAS pin exceeds the under voltage lockout threshold (UVLO_{rise}). Once the voltage at BIAS exceeds UVLO_{rise}, the QOD FET is turned ON to pull OUT to ground and the pass-FET is turned off.

When a logic high is applied at the EN pin, the IC disables the QOD FET and charges the output capacitance at a controlled slew rate. Once the output voltage is close to the input voltage, the pass FET is turned on completely to achieve low on-resistance. Pulling EN low will turn off the pass-FET and turn on the QOD FET to discharge the output capacitor.

If at anytime during operation, the junction temperature of the IC exceeds the over temperature set point (_{TOTLO}), the device turns off the pass-FET and turns on the QOD FET. It remains latched in the off-state till the EN pin is toggled externally.

9. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{IN}	input voltage	pin IN	-0.3	1.2	V
I _{OUT}	output current	pin OUT	_	1.5	А
V _{BIAS}	input voltage	pin BIAS	-0.3	6.0	V
V _{EN}	input voltage	pin EN	-0.3	6.0	V
TJ	maximum junction temperature	[1]	-40	125	°C
T _{stg}	storage temperature		-65	150	°C

[1] T_{J(max)} internally limited by OTP threshold.

10. ESD ratings

Table 5. ESD rating	gs
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Symbol	Parameter	Conditions	Value	Unit
V _{ESD}	electrostatic discharge voltage	HBM: ANSI/ESDA/JEDEC JS-001 class 2	± 2000	V
		CDM: ANSI/ESDA/JEDEC JS-002 class C2a	± 500	V

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11. Recommended operating conditions

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Symbol	Parameter	Conditions	Min	Max	Unit
V _{IN}	input voltage	pin IN	0.5	1.0	V
V _{OUT}	output voltage	pin OUT	0.5	1.0	V
V _{BIAS}	input voltage	pin BIAS	2.3	5.0	V
V _{EN}	input voltage	pin EN [1]	0	5.0	V
TJ	junction temperature		-40	105	°C

Table 6. Recommended operating conditions

[1] Although the EN pin voltage is rated up to 5 V, the logic high and low voltages need to meet the ON and OFF thresholds stated in the Electrical Characteristics in <u>Section 14</u>.

12. Recommended components

Table 7. Recommended components

Effective capacitance at output

Symbol	Parameter	Conditions	Min	Max	Unit
C _{OUT}	output capacitance	pin OUT; V _{OUT} = 1.0 V [1]	1	60	μF

[1] see <u>Section 16.2</u>

13. Thermal characteristics

Table 8. Thermal information

Measured as per JEDEC standard JESD51-7 on a 4-layer, 1.6 mm FR4 PCB with 2 oz Cu for top and bottom layers and 1 oz Cu for inner layers with no vias. Pads are connected to 0.25 mm copper traces.

Symbol	Parameter	WLCSP8_SOT8068	Unit
R _{OJA}	junction to ambient thermal resistance	101	°C/W
Ψ_{JT}	junction-to-top characterization parameter	4.1	°C/W

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14. Electrical characteristics

Table 9. Electrical characteristics

 T_J = -40 °C to +105 °C unless otherwise specified. V_{IN} =1.0 V, V_{BIAS} = 3.4 V, unless otherwise specified.

Symbol	Parameter	Conditions		T _J = -4	Unit		
				Min	Typ[1]	Max	
IN and C	OUT pins						
I _{IN(OFF)} input leakage current when OFF	input leakage current	V _{IN} = 1.0 V, EN = LO, T _J = -40 °C to +85 °C		-	0.12	6.20	μA
	V _{IN} = 1.0 V, EN = LO, T _J = +27 °C		-	0.12	0.36	μA	
		V _{IN} = 1.0 V, EN = LO, T _J = +45 °C		-	0.24	0.59	μA
		V _{IN} = 1.0V, EN = LO, T _J = +85 °C		-	1.50	6.20	μA
I _{IN,Q}	quiescent current	V _{IN} = 1.0 V, EN = HI, OUT = open		-	0.14	3.50	μA
I _{INRUSH}	inrush current	V_{IN} = 1.0V, EN goes from low to high, C_{OUT} = 60 μF	[2]	-	0.77	1.20	А
BIAS input pin							
UVLO _{rise}	BIAS UVLO rising threshold			2.12	2.19	2.26	V
UVLO _{hys}	BIAS UVLO hysteresis		[2]	-	0.10	-	V
I _{SH,BIAS}	BIAS shutdown	EN = LO, T _J = -40 °C to +85 °C		-	1.06	2.14	μA
	current	EN = LO, T _J = +27 °C		-	1.06	1.71	μA
		EN = LO, T _J = +45 °C		-	1.11	1.82	μA
		EN = LO, T _J = +85 °C		-	1.22	2.14	μA
I _{Q,BIAS}	BIAS quiescent current	EN = HI		-	10	15.1	μA
EN inpu	t pin						
V _{EN,HI}	EN High threshold	Load switch goes from OFF to ON		0.72	-	-	V
V _{EN,LO}	EN Low threshold	Load switch goes from ON to OFF		-	-	0.37	V
V _{EN,HYS}	EN hysteresis voltage	V _{IN} = 1.0 V, EN = HI, OUT = open		-	77	-	mV
Quick O	utput Discharge FET	(QOD)					
R _{QOD}	quick output discharge FET resistance	V _{OUT} = 1.0 V, EN = LO		-	8	18	Ω
Power F	ET						
R _{DS,ON}	ON-state resistance	V _{BIAS} - V _{OUT} = 1.6 V, I _{OUT} = 1.5 A, T _J = 25 °C		-	11	12.6	mΩ
		V_{BIAS} - V_{OUT} = 1.6 V, I_{OUT} = 1.5 A, T_{J} = 85 °C	[2]	-	13.4	16	mΩ
		V _{BIAS} - V _{OUT} = 1.3 V, I _{OUT} = 1.5 A, T _J = 85 °C	[2]	-	14.7	18	mΩ
Over Ter	mperature Protection	(OTP)					
T _{OTLO}	over temperature lockout threshold	EN = HI, load switch goes from ON to OFF	[2]	115	125	139	°C

[1] Typical numbers are mean values at 25 °C.

[2] Obtained through simulation and characterization, but not tested in production.

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15. Dynamic characteristics

Table 10. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_{IN} = 1.0 \text{ V}, V_{BIAS} = 3.4 \text{ V}, V_{EN} = 0 \text{ V}/1.2 \text{ V}, C_{OUT} = 60 \mu\text{F}, R_{OUT} = \text{open, unless otherwise specified.}$

For timing diagrams and test circuit see Fig. 4 and Fig. 5; See also additional graphs in Section 15.2 and Section 15.3.

Symbol Parameter		Conditions		T _J = -4	10 °C to +	105 °C	Unit
				Min	Typ[1]	Max	
t _{d,rise}	EN rise delay time	EN rising edge to V _{OUT} = 10 %		-	48	-	μs
t _{rise}	output rise time	V _{OUT} rising from 10 % to 90 %		-	69	-	μs
t _{ON}	total turn-on Time	EN rising edge to V _{OUT} = 90 %		-	114	-	μs
T _{ENH}	total time to enhance the power FET	EN rising edge to R_{on} within 10 % of steady state value		-	146	200	μs
t _{d,fall}	EN fall delay time	EN falling edge to V _{OUT} = 90 %		-	51	-	μs
t _{fall}	output fall time	V _{OUT} falling from 90 % to 10 %		-	432	-	μs
t _{OFF}	total turn-off time	EN falling edge to V _{OUT} = 10 %		-	495	-	μs
T _{ENL}	total time to turn-off the power FET	EN falling edge to power FET off	[2]	-	-	5	μs
t _{HI,EN}	enable high pulse width	EN rising edge to EN falling edge	[2]	4	-	-	μs
t _{LO,EN}	enable LOW pulse width	EN falling edge to EN rising edge	[2]	5	-	-	μs

[1] Typical values are measured at $T_J = 25$ °C.

[2] Design guidance for customer.

15.1. Waveforms and test circuit





15.2. Typical characteristics

Unless otherwise noted, V_{IN} = 1.0 V, C_{IN} = 1.0 μ F, V_{BIAS} = 3.4 V, C_{BIAS} = 0.1 μ F, C_{OUT} = 66 μ F, R_{OUT} = open







15.3. Typical waveforms

Unless otherwise noted, V_{IN} = 1.0 V, C_{IN} = 1.0 μ F, V_{BIAS} = 3.4 V, C_{BIAS} = 0.1 μ F, C_{OUT} = 66 μ F, R_{OUT} = open.



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16. Application information

16.1. Typical application diagram



16.2. Inrush current

The NPS1000 does not directly control the inrush current at startup. Instead, it controls the output slew rate by controlling the slew rate of the gate voltage for the power FET. The pass device acts as a source follower during startup and the output slew rate follows the slew rate of the pass-FET's gate voltage. The inrush current at any given condition is thus a function of the input voltage and the load capacitance. The following graphs (Fig. 26 and Fig. 27) show how the peak inrush current varies with the operating conditions.



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17. Design and assembly recommendations

17.1. PCB design guidelines

For best performance, all traces must be kept as short as possible. The input and output capacitors must be placed close to the device to minimize effects of parasitic trace inductances on normal operation. Using wide traces for VIN, VOUT, and GND helps minimize the parasitic electrical effects.

A minimum 1 μ F capacitor is recommended from IN to GND as well as OUT to GND, and these should be placed as close to the IC as possible as shown in <u>Section 17.2</u>.

17.2. PCB layout example

A typical layout example if shown in Fig. 28. At least a 2-layer PCB is recommended for best layout practices. The top layer is used for routing the signals as shown in the figure (gray areas are copper planes on the top layer). The bottom layer (or second layer in a multi-layer PCB) is used for a copper plane connected to GND (yellow area). Multiple vias are recommended (number depends on manufacturing guidelines).



18. Package outline





19. Abbreviations

Table 11. Abbreviations		
Acronym	Description	
CDM	Charged-Device Model	
CMOS	Complementary Metal Oxide Semiconductor	
НВМ	Human Body Model	
ESD	ElectroStatic Discharge	

20. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NPS1000 v.1	20240329	Product data sheet	-	-

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21. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

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